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ON Semiconductor®

FSA3051 — High Performance SPDT Analog Switch with Over-Voltage Tolerance

Features

- Low On Capacitance: 7.7 pF Typical
- Low On Resistance: 6 Ω Typical
- Low Pow er Consumption: 1 µA Maximum
 - 15 μA Maximum I_{CCT} over an Expanded Voltage Range (V_{IN}=1.8 V, V_{CC}=5.5 V)
- Wide -3 db Bandw idth: 1.0 GHz
- Packaged in Ultra Small 6-Lead TMLP
- Broad V_{CC} Operating Range: 1.6 V to 5.5 V
- Over-Voltage Tolerance (OVT) on all Data Ports up to 6 V without External Components

Applications

- Cell Phone, PDA, Digital Camera, and Notebook
- LCD Monitor, TV, and Set-Top Box

Description

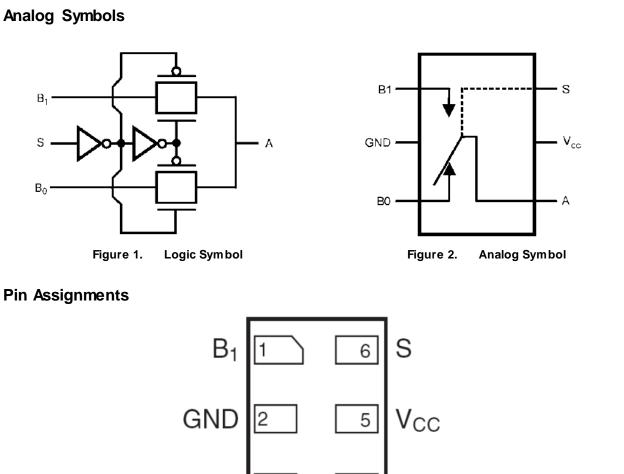
The FSA3051 is a 6 Ω , bi-directional, low-power, two-port, high-speed, Single Pole / Double Throw (SPDT) analog switch. It features an extremely low on capacitance (C_{ON}) of 7.7 pF and wide bandwidth of 1.0 GHz.

The FSA3051 contains special circuitry on the switch VO pins for applications where the V_{CC} supply is powered-off (V_{CC} =0 V), which allows the device to withstand an over-voltage condition. This device is designed to minimize current consumption even when the control voltage applied to the select (S) pin is low er than the supply voltage (V_{CC}). This feature is especially valuable to ultra-portable applications, such as cell phones, allowing for direct interface with the general-purpose VOs of the baseband processor. Other applications include switching in portable cell phones, PDAs, digital cameras, printers, and notebook computers.

Ordering Information

Part Number	Top Mark	Operating Temperature Range	Package
FSA3051TMX	NT	-40 to +85°C	6-Lead, Dual, Ultra-ultrathin Molded Leadless Package (TMLP), 1.0 x 1.0 mm. Top left unit orientation in carrier tape.
FSA3051TMX-F147	NT	-40 to +85°C	6-Lead, Dual, Ultra-ultrathin Molded Leadless Package (TMLP), 1.0 x 1.0 mm. Bottom left unit orientation in carrier tape.

MicroPak[™] is a trademark of ON Semiconductor Corporation.



Pin Definitions

UMLP Pin#	Name	Description
1	B ₁	Data Port
2	GND	Ground
3	B ₀	Data Port
4	А	Data Port
5	Vcc	Supply Voltage
6	S	Sw itch Select

4

6-Lead TMLP (Top-Through View)

A

 B_0

Figure 3.

3

Truth Table

S	Function
LOW	B ₀ connected to A
HIGH	B ₁ connected to A
Notes: 1. LOW ≤V _{IL} .	

2. HIGH ≥V_{IH}.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit	
Vcc	Supply Voltage		-0.5	6.0	V
VCNTRL	DC Input Voltage ⁽³⁾		-0.5	Vcc	V
Vsw	DC Switch I/O Voltage ⁽³⁾		-0.50	6.00	V
lıк	DC Input Diode Current		-50		mA
Юит	DC Output Current			50	mA
T _{STG}	Storage Temperature		-65	+150	°C
MSL	Moisture Sensitivity Level (JEDEC J-STD-020A)			1	Level
		All Pins	2		
ESD	Human Body Model, ANSI/ESDA/JEDEC JS-001-2012	VO to GND	2		kV
EOD		Pow er to GND	2		۳V
	Charged Device Model, JEDEC: JESD22-C107	1	1		

Note:

3. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
Vcc	Supply Voltage	1.6	5.5	V
VCNTRL	Control Input Voltage (S) ⁽⁴⁾	0	Vcc	V
V _{SW}	Switch I/O Voltage	-0.5	5.5	V
TA	Operating Temperature	-40	+85	°C

Note:

4. The control input must be held HIGH or LOW and it must not float.

DC Electrical Characteristics

All typical value are at TA=25°C unless otherwise specified.

Symbol	Parameter	Condition	V _{cc} (V)	T _A =- 40°C to +85°C			Unit
	Parameter			Min.	Тур.	Max.	Onit
Vıĸ	Clamp Diode Voltage	l _{IN} =-18 mA	3.0			-1.2	V
Max	Innut Valtage Lligh		1.8 to 4.3	1.3			V
VIH	V _{IH} Input Voltage High		4.3 to 5.5	1.7			v
VIL	Input Voltage Low		1.8 to 4.3			0.5	V
VIL	Input Voltage Low		4.3 to 5.5			0.7	v
IN	Control Input Leakage	V _{CNTRL} =0 to V _{CC}	1.8	-1		1	μA
ЧN	Control Input Leakage	V CNTRL=0 t0 V CC	5.5	-1		1	μA
loz	Off State Leakage	V _{SW} =0 V to V _{CC}	1.8	-2		2	μA
ЮZ		V _{SW} =0 V to 3.6 V	5.5	-2		2	μΑ
I OFF	Pow er-Off Leakage Current (All I/O Ports)	$V_{SW}\!\!=\!\!0$ V to 4.3 V, $V_{CC}\!\!=\!\!0$ V Figure 5	0	-2		2	μΑ
Devi	RON Switch On Resistance ⁽⁵⁾	V _{SW} =0.4 V, I _{ON} =-8 mA Figure 4	3.0		4	10	
R _{ON}	Switch On Resistance	V _{SW} =1.8 V, I _{ON} =-8 mA Figure 4	3.0		6	10	Ω
Devi	Sw itch On Resistance ⁽⁵⁾	V _{SW} =0.4 V, I _{ON} =-8 mA Figure 4	1.8		6	10	
Ron	Switch On Resistance	V _{SW} =1.8 V, I _{ON} =-8 mA Figure 4	1.8		14	25	Ω
ΔR _{ON}	On Resistance Match	$\sqrt{2}$	3.0		35		
ANON	Betw een Channels ^(5,6)	$V_{SW}=0.4 V$, $I_{ON} = -8 mA$	1.8		40		mΩ
lcc	Quiescent Supply Current	V _{CNTRL} =0 or V _{CC} , l _{OUT} =0	5.5			1	μΑ
		V _{CNTRL} =1.8 V	3.0			10	
Ісст	Increase in I _{CC} Current per Control Voltage and V _{CC}	V _{CNTRL} =2.6 V	5.5			10	μA
		V _{CNTRL} =1.8 V	5.5			15	

Notes:

5. Measured by the voltage drop between A and Bn pins at the indicated current through the switch. On resistance is determined by the low er of the voltage on the two (A or Bn ports). $\Delta R_{ON} = R_{ON}$ maximum - R_{ON} minimum measured at identical V_{CC}, temperature, and voltage levels.

6.

Guaranteed by characterization. 7.

FSA3051 — High Performance SPDT Analog Switch with Over Voltage Tolerance

AC Electrical Characteristics⁽⁸⁾

All typical value are for V_{CC}=3.3 V at T_A=25 ^{\circ}C unless otherwise specified.

Symbol	Parameter	Condition	V _{cc} (V)	T _A =- 40°C to +85°C			1.1
		Condition		Min.	Тур.	Max.	Unit
ton	Turn-On Time	RL=50 Ω, CL=5 pF, V _{SW} =0.8 V,	3.0 to 3.6		34		ns
LON	S to Output	Figure 6, Figure 7	1.8		110		115
toff	Turn-Off Time	RL=50 Ω, CL=5 pF, V _{SW} =0.8 V, 3	3.0 to 3.6		23		ns
UFF	S to Output	Figure 6, Figure 7	1.8		50		115
t _{PD} Propagation Delay	Propagation Delay	CL=5 pF, RL=50 Ω , Figure 6, Figure 8	3.3		0.2		ns
	Propagation Delay		1.8		0.3		
t _{BBM}	Break-Before-Make	$R_{L}{=}50~\Omega,~C_{L}{=}5~pF,$ $V_{SW1}{=}V_{SW2}{=}0.8~V,$ Figure 9	3.0 to 3.6	15		50	ns
(BBIM	Dieak-Dei Oie-Iwake		1.8			100	
O _{IRR}	Off Isolation	R_{L} =50 Ω , f=240 MHz, Figure 11	1.8		-20		dB
OIRR			3.0 to 3.6		-23		uВ
Xtalk	Crosstalk	sstalk $R_L=50 \Omega$, f=240 MHz, Figure 12	1.8		-18		dB
	CIUSSIAIN		3.0 to 3.6		-23		dB
		RL=50 Ω , CL=0 pF, V _{SW} =0.4 V	1.8		810		MHz
BW	-3 db Bandw idth	RL=50 Ω , CL=0 pF, Figure 10	3.0 to 3.6		1		GHz
		R _L =50 Ω , C _L =5 pF, Figure 10			750		MHz

Note:

8. Guaranteed by characterization. Not production tested.

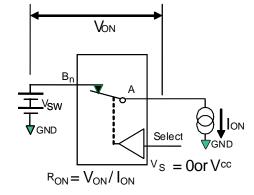
Capacitance ⁽⁹⁾

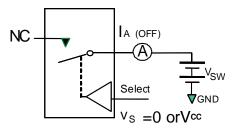
Symbol	Parameter	Condition	V _{cc} (V)	T _A =- 40°C to +85°C			
				Min.	Тур.	Max.	Unit
Cin	Control Pin Input Capacitance		0		1.5		
	f=1 MHz,	3.0		7.7			
	A Port On Consoitance	f=240 MHz, Figure 14	3.3		7.7		
CON	A Port On Capacitance	f=1 MHz,	1.8		10.0		_
		f=240 MHz, Figure 14	1.8		5.0		pF
		f=1 MHz	3.0		3.3		
C _{OFF} I	Bn Port Off Capacitance	f=240 MHz, Figure 13	3.3		3.3		
		f=1 MHz	1.8		5.0		
		f=240 MHz, Figure 13	1.8		4.0		

Note:

9. Not production tested.

Test Diagrams





**Each switch port is tested separately





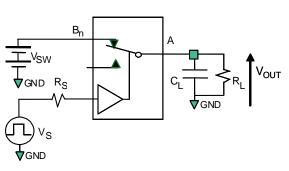
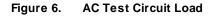


Figure 4.

 $\rm R_L$, $\rm R_S$, and $\rm C_L$ are functions of the application environment (see AC Tables for specific values) $\rm C_L$ includes test fixture and stray capacitance.

On Resistance



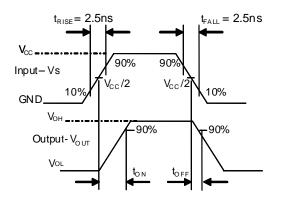


Figure 7. Turn-On / Turn-Off Waveforms

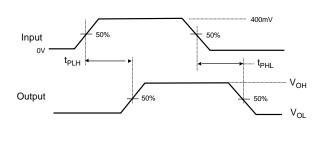
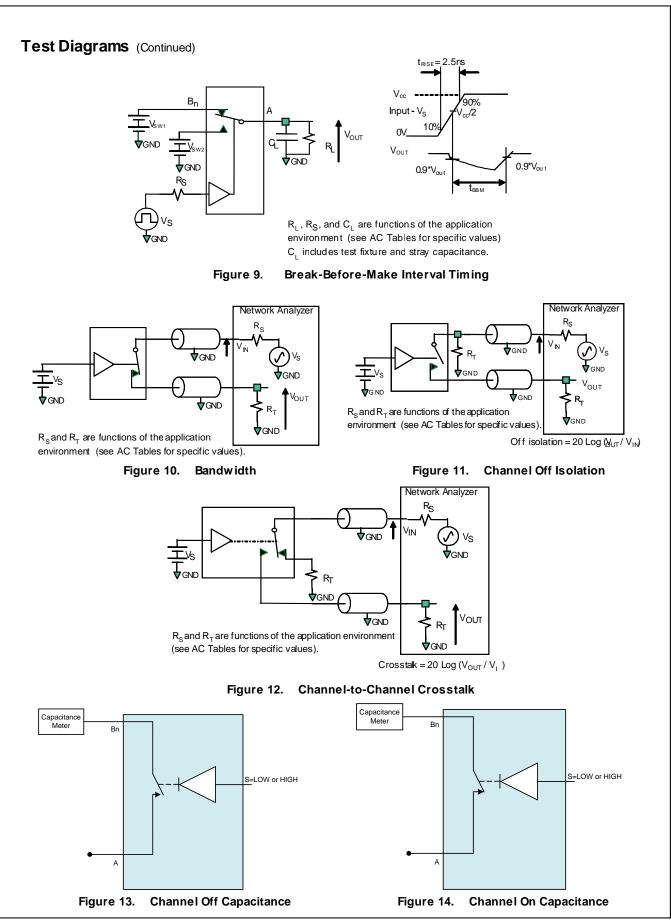
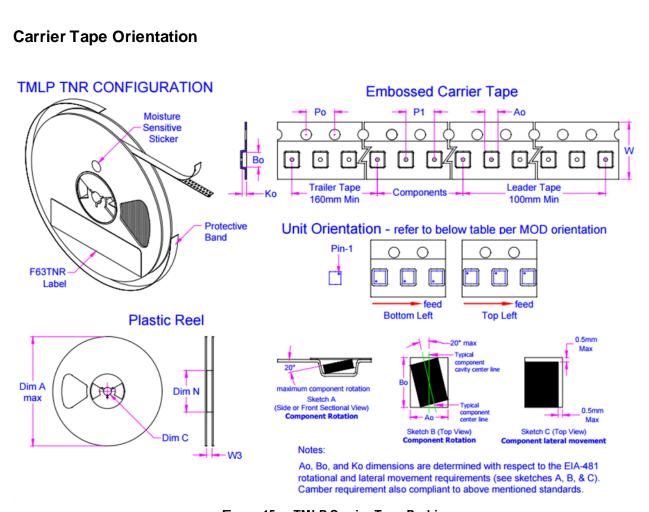


Figure 8. Propagation Delay (t_Rt_F - 500 ps)

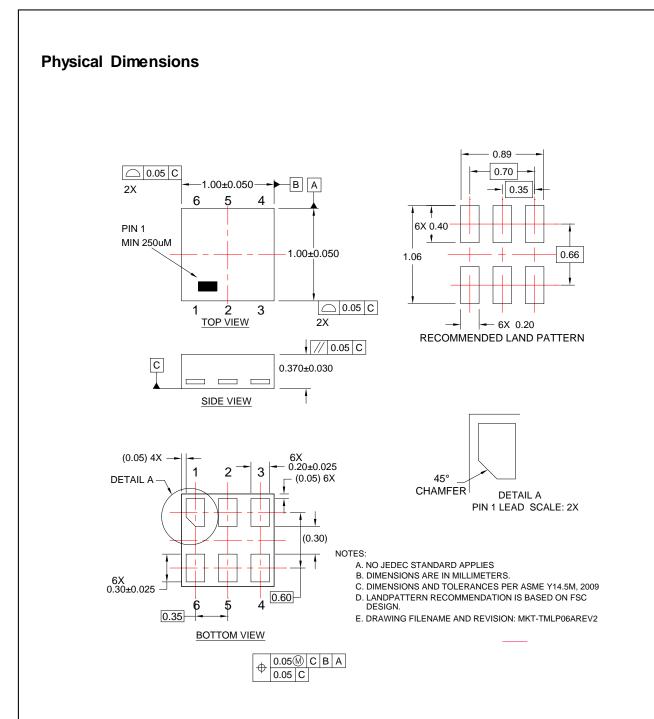


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Part Number	Unit Orientation
FSA3051TMX	Top Left
FSA3051TMX-F147	Bottom Left



6-Lead, Dual, Ultra-ultrathin Molded Leadless Package (TMLP), 1.0 x 1.0 mm

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